# imall

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## Contact us

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DMN61D9UDW

### **Product Summary**

V(BR)DSS	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
60V	2Ω @ V <sub>GS</sub> = 5.0V	350mA
60 V	2.5Ω @ V <sub>GS</sub> = 2.5V	330IIIA

### Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- Motor Control
- Power Management Functions

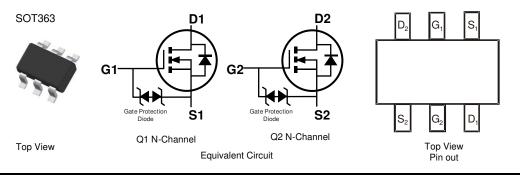
#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN61D9UDW-7	SOT363	3000/Tape & Reel
DMN61D9UDW-13	SOT363	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**

	D.	G, S,		ſ	$D_{2}$	G,	S.
		YM			-	<u> ~' </u> AB YN	- 1
	-	101 101				Y 8A	
	<b>S</b> <sub>2</sub>	G <sub>2</sub> D <sub>1</sub>			S <sub>2</sub>	G2	D,
Key	Ľ			L	-	Ľ	لنا
	0011	0015	0010			0047	

9D1 or DAB = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M = Month (ex: 9 = September)

#### Date Code Key

Balo Bodo H	≎,											
Year	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	В	С	D	E	F	G	Н		J	K	L	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	60	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) $V_{GS} = 5V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	350 290	mA
Maximum Continuous Body Diode Forward Curre	ls	0.4	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	I <sub>DM</sub>	1.2	А		

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	320	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	397	°C/W
Total Power Dissipation (Note 6)		PD	410	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	306	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	•					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS		-	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	—	1.0	V	$V_{DS} = 10V, I_D = 250 \mu A$
			1.2	2.0		$V_{GS} = 5.0V, I_D = 0.05A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	1.6	2.5	Ω	$V_{GS} = 2.5V, I_D = 0.05A$
			2.5	3.5		$V_{GS} = 1.8V, I_D = 0.05A$
Forward Transconductance	Y <sub>fs</sub>	200	_	_	mS	V <sub>DS</sub> =10V, I <sub>D</sub> = 0.2A
Diode Forward Voltage	V <sub>SD</sub>	_	0.75	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)	•					
Input Capacitance	Ciss		28.5	_	pF	
Output Capacitance	Coss		3.9	_	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		2.5	_	pF	1 = 1.000112
Gate Resistance	Rg	_	65		Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg	—	0.4	_	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	0.1	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1		nC	I <sub>D</sub> = 250mA
Turn-On Delay Time	t <sub>D(ON)</sub>		2.1	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	1.8	_	ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V,
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	14.4	—	ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t <sub>F</sub>	_	8.4		ns	]

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

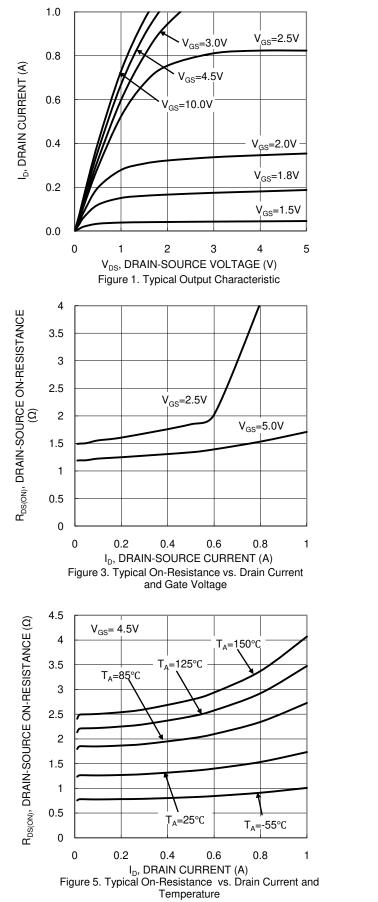
6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.

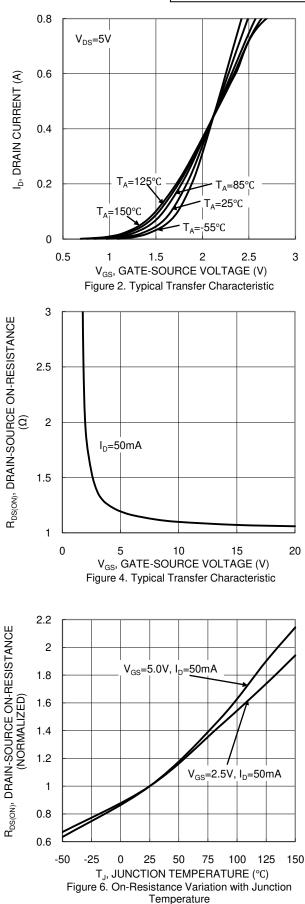
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



#### DMN61D9UDW



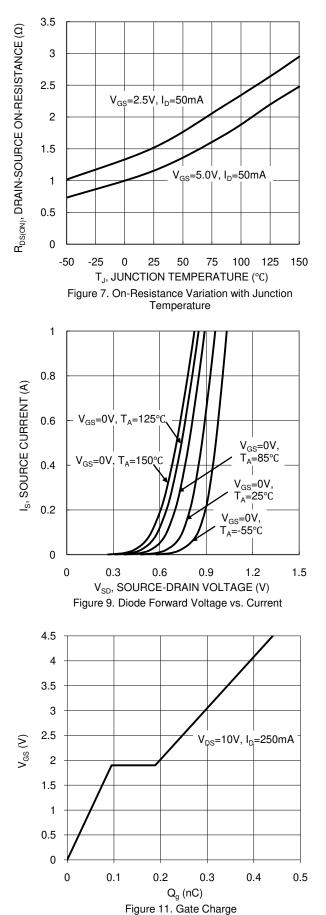


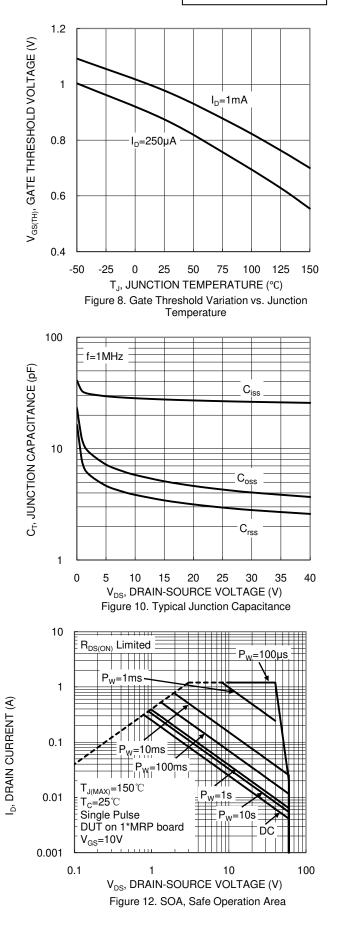
NEW PRODUCT

DMN61D9UDW Document number: DS38032 Rev. 2 - 2



#### DMN61D9UDW

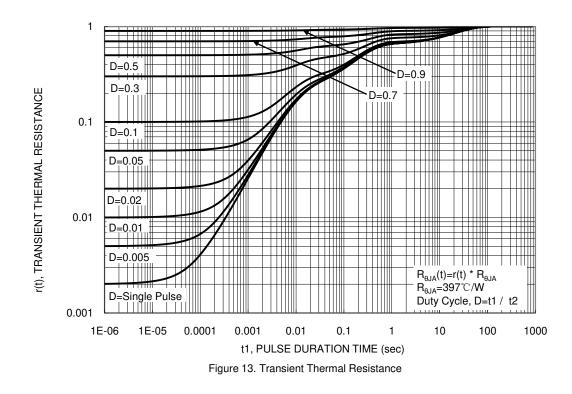




NEW PRODUCT

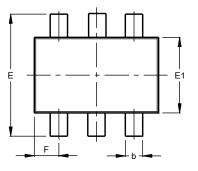
DMN61D9UDW Document number: DS38032 Rev. 2 - 2 4 of 6 www.diodes.com

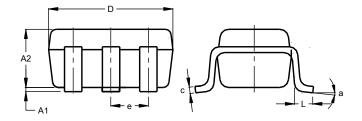




### Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



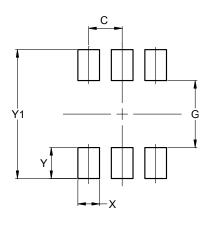


	SOT363								
Dim	Min	Тур							
A1	0.00	0.10	0.05						
A2	0.90	1.00	1.00						
b	0.10	0.30	0.25						
С	0.10	0.11							
D	1.80	2.20	2.15						
E	2.00	2.20	2.10						
E1	1.15	.15 1.35 1.3							
е	0	).650 E	SC						
F	0.40	0.45	0.425						
L	0.25	0.40	0.30						
а	<b>a</b> 8°								
All	Dimen	sions	in mm						



### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Value (in mm)
0.650
1.300
0.420
0.600
2.500

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